



A. HE83116B Introduction

HE83116B is a member of 8-bit Micro-controller series developed by King Billion Electronics Ltd. This IC build-in 128-dot LCD driver, and also have 16-bit I/O port. The built-in OP comparator can be used with (light、voice、temperature、humidity) sensor and used as battery low detection. And the 7-bit current-type D/A converter and PWM device provide the complete speech output mechanism. The 64K ROM Size can be used in the storage of speech (20 seconds at 3Kbytes per second), graphic, text etc. This IC is applicable to the small systems such as calculating machine, perpetual calendar, digital watch etc..

The instruction set of HE83116B are quite easy to learn and simple to use. Only about thirty instructions with four-type addressing mode are provided. Most of instructions take only 3 oscillator clocks (machine cycles). The processing power is enough to most of battery operation system.

B. HE83116B Features

- Operation Voltage : 2.4V – 5.5V
- System Clock : DC ~ 8MHz @ 5.0V
- DC ~ 4MHz @ 2.4V
- Internal ROM : 64K Bytes(64K Program ROM)
- Internal RAM : 256 Bytes.
- Dual Clock System : Normal (Fast) clock : 32.768K ~ 8MHz
- Slow clock : 32.768KHz
- Operation Mode : DUAL、FAST、SLOW、IDLE、SLEEP Mode.
- With WDT (WATCH DOG TIMER) to prevent deadlock condition..
- 16 bit Bi-directional I/O port. Mask Option can select PUSH-PULL or OPEN DRAIN output mode for each I/O pin.
- One built-in OP comparator.
- 128 dots LCD driver (A、B TYPE selectable).
- One 7-bit current-type DAC output.
- PWM device.
- Two external interrupts and two internal timer interrupts.
- Two 16-bit timer.
- Instruction set : 32 instructions, 4 addressing mode. 8-bit DATA POINTER for RAM and 16-bit TABLE POINTER for ROM.

C. Internal Block

Please always take in mind that ICE is different from IC. ICE is the whole set of HE80000 series IC, but each IC is a subset of ICE. Never use any hardware resource that real IC didn't have, especially RAM and register. KBIDS and compiler cannot prevent user to use some hardware resource that didn't exist. Please check the following table and refer the abbreviation in HE80000 user's manual.



I.F.C.	E.S.C.	I.P.R.	PROM	DROM	TP	TP+1	RAM	PP	DP	I/O	DTMF	WDT	Timer
⊙	⊙	⊙	64KB	—	16-bit	⊙	256B	—	8-bit	16	—	⊙	T1,T2
DAO	OP	PWM	LCD	COM*SEG	Bias	Rgr	ChrgPmp	LV2	LR	LVG	REC	S.R.	
—	⊙	⊙	128	4*32	1/3	—	1,3/2,3	⊙	—	—	—	—	

D. Pin Description

Pin #	Pin name	I/O	Function	Description
55 54	FXI, FXO	B, O	External fast clock pin. Connecting to crystal or RC to generate 32.768 kHz ~ 8MHz frequency.	Mask option setting : MO_FCK/SCKN= 00 : Slow Clock only 01 : Illegal 10 : Dual Clock 11 : Fast Clock only MO_FOSCE = 0 : Internal fast osc. = 1 : External fast osc.
58 57	SXI, SXO	I, O	External slow clock pin. Connecting with 32768 Hz crystal or resistor as slow clock and providing clock source for LCD display, TIMER1, Time-Base and other internal blocks.	MO_FXTAL= 0 : RC osc. for fast clock = 1 : X'tal osc. for fast clock MO_SXTAL= 0 : RC for 32768 Hz clock = 1 : X'tal for 32768 Hz clock Use OP1 and OP2 to switch among different operation mode (NORMAL, SLOW, IDEL and SLEEP). In Dual Clock mode, the main system clock is still the Fast Clock. The 32768 Hz clock is for LCD and Timer 1 only.
53	RSTP_N	I	System Reset.	Level trigger, active low. Except for using this pin, using mask option (MO_PORE=1) could enable IC build-in power-on reset circuit. Besides, MO_WDTE can set Watch Dog Timer : MO_WDTE=0 : Disable Watch Dog Timer =1 : Enable Watch Dog Timer
56	TSTP_P	I	Test Pin	Please bond this pin and add a test point on PCB for debugging. Leave this pin floating is OK.
68..71 1..4	PRTC[7:0]	B	8-pin bi-directional I/O port.	Mask options : MO_CPP[7..0]=1 ~ Push-pull. =0 ~ Open-drain. Output must be “1” before reading whenever use them as input (No tri-state structure).
60..67	PRTD[7:0]	B	8-pin bi-directional I/O port. PRTD[7..2] as wake-up pin. PRTD[7..6] as external interrupt pin.	Mask options : MO_DPP[7..0]=1 ~ Push-pull. =0 ~ Open-drain. Output must be “1” before reading whenever use them as input (No tri-state structure).
39..42	COM[3:0]	O	LCD COMmon Output	LCD Data filled from F0H, please refer the LCD RAM map.
7..38	SEG[31:0]	O	LCD SEGment Output	
44	LC2	B	Charge Pump Switch 2	Add one 0.1 μF capacitor between LC1 and LC2. Please refer the application circuit.
43	LC1	B	Charge Pump Switch 1	
45	LV3	B	Charge Pump V3	LV3 < 9 Volts. Please refer the application circuit.
46	LV2	B	Charge Pump V2	
48	LV1	B	Charge Pump V1	
5	PWMP	O	The PWM positive output can drive speaker or buzzer directly.	Set the bit2 of VOC register as one to turn on PWM.



Pin #	Pin name	I/O	Function	Description
6	PWMN	O	The PWM positive output can drive speaker or buzzer directly.	Set the bit2 of VOC register as one to turn on PWM.
49	VO	O	D/A output.	Bit 1 of VOC = '1', Turn on DA
50	OPIN	I	OPAMP negative input pin.	Built-in OP comparator. Set Bit 0 of VOC = '1', Turn on OP
51	OPIP	I	OPAMP positive input pin.	
52	OPO	O	OPAMP output pin.	
59	VDD	P	Positive Power Input	Adding 0.1 μ F capacitor as by-pass capacitor is between VDD and GND is necessary.
47	GND	P	Power Ground Input	

E. LCD RAM Map

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F0H	SEG1	SEG0	F8H	SEG17	SEG16
	COM[3:0]	COM[3:0]		COM[3:0]	COM[3:0]
F1H	SEG3	SEG2	F9H	SEG19	SEG18
	COM[3:0]	COM[3:0]		COM[3:0]	COM[3:0]
F2H	SEG5	SEG4	FAH	SEG21	SEG20
	COM[3:0]	COM[3:0]		COM[3:0]	COM[3:0]
F3H	SEG7	SEG6	FBH	SEG23	SEG22
	COM[3:0]	COM[3:0]		COM[3:0]	COM[3:0]
F4H	SEG9	SEG8	FCH	SEG25	SEG24
	COM[3:0]	COM[3:0]		COM[3:0]	COM[3:0]
F5H	SEG11	SEG10	FDH	SEG27	SEG26
	COM[3:0]	COM[3:0]		COM[3:0]	COM[3:0]
F6H	SEG13	SEG12	FEH	SEG29	SEG28
	COM[3:0]	COM[3:0]		COM[3:0]	COM[3:0]
F7H	SEG15	SEG14	FFH	SEG31	SEG30
	COM[3:0]	COM[3:0]		COM[3:0]	COM[3:0]



G. Bonding Pad Location

PIN Number	PIN Name	X Coordinate	Y Coordinate	PIN Number	PIN Name	X Coordinate	Y Coordinate
1	PRTC[3]	-1154.77	924.54	37	SEG[1]	1153.42	-943.42
2	PRTC[2]	-1154.77	809.54	38	SEG[0]	1153.42	-828.42
3	PRTC[1]	-1154.77	694.54	39	COM[3]	1153.42	-713.42
4	PRTC[0]	-1154.77	579.54	40	COM[2]	1153.42	-598.42
5	PWMP	-1154.78	462.49	41	COM[1]	1153.42	-483.42
6	PWMN	-1154.78	347.79	42	COM[0]	1153.42	-368.42
7	SEG[31]	-1154.78	235.14	43	LC1	1153.42	-253.42
8	SEG[30]	-1154.78	120.14	44	LC2	1153.42	-138.42
9	SEG[29]	-1154.78	5.14	45	LV3	1153.42	-23.42
10	SEG[28]	-1154.78	-109.86	46	LV2	1153.42	91.58
11	SEG[27]	-1154.78	-224.86	47	GND	1153.42	206.58
12	SEG[26]	-1154.78	-339.86	48	LV1	1153.42	321.58
13	SEG[25]	-1154.78	-454.86	49	VO	1153.42	436.58
14	SEG[24]	-1154.78	-569.86	50	OPIN	1153.42	551.58
15	SEG[23]	-1154.78	-684.86	51	OPIP	1153.42	666.58
16	SEG[22]	-1154.78	-799.86	52	OPO	1153.42	781.58
17	SEG[21]	-1154.78	-914.86	53	RSTP_N	1153.42	896.58
18	SEG[20]	-1049.98	-1180.86	54	FXO	988.66	1179.60
19	SEG[19]	-934.98	-1180.86	55	FXI	873.66	1179.60
20	SEG[18]	-819.98	-1180.86	56	TSTP_P	758.66	1179.60
21	SEG[17]	-704.98	-1180.86	57	SXO	643.66	1179.60
22	SEG[16]	-589.98	-1180.86	58	SXI	528.66	1179.60
23	SEG[15]	-474.98	-1180.86	59	VDD	413.66	1179.60
24	SEG[14]	-359.98	-1180.86	60	PRTD[7]	298.66	1179.59
25	SEG[13]	-244.98	-1180.86	61	PRTD[6]	183.66	1179.59
26	SEG[12]	-129.98	-1180.86	62	PRTD[5]	68.66	1179.59
27	SEG[11]	-14.98	-1180.86	63	PRTD[4]	-46.34	1179.59
28	SEG[10]	100.02	-1180.86	64	PRTD[3]	-161.34	1179.59
29	SEG[9]	215.02	-1180.86	65	PRTD[2]	-276.34	1179.59
30	SEG[8]	330.02	-1180.86	66	PRTD[1]	-391.34	1179.59
31	SEG[7]	445.02	-1180.86	67	PRTD[0]	-506.34	1179.59
32	SEG[6]	560.02	-1180.86	68	PRTC[7]	-621.35	1179.60
33	SEG[5]	675.02	-1180.86	69	PRTC[6]	-736.36	1179.60
34	SEG[4]	790.02	-1180.86	70	PRTC[5]	-851.37	1179.60
35	SEG[3]	905.02	-1180.86	71	PRTC[4]	-966.38	1179.60
36	SEG[2]	1153.42	-1058.42				



H. DC/AC Characteristics

Absolute Maximum Rating

Item	Sym.	Rating	Condition
Supply Voltage	V_{dd}	-0.5V ~ 8V	
Input Voltage	V_{in}	-0.5V ~ $V_{dd}+0.5V$	
Output Voltage	V_o	-0.5V ~ $V_{dd}+0.5V$	
Operating Temperature	T_{op}	0 ⁰ C ~ 70 ⁰ C	
Storage Temperature	T_{st}	-50 ⁰ C ~ 100 ⁰ C	

Recommended Operating Conditions

Item	Sym.	Rating	Condition
Supply Voltage	V_{dd}	2.4V ~ 5.5V	
Input Voltage	V_{ih}	0.9 V_{dd} ~ V_{dd}	
	V_{il}	0.0V ~ 0.1 V_{dd}	
Operating Frequency	F_{max}	8MHz	$V_{dd}=5.0V$
		4MHz	$V_{dd}=2.4V$
Operating Temperature	T_{op}	0 ⁰ C ~ 70 ⁰ C	
Storage Temperature	T_{st}	-50 ⁰ C ~ 100 ⁰ C	



Test Condition: TEMP=25°C, VDD=3V+/-10%, GND=0V

	PARAMETER		CONDITION	MIN	TYP	MAX	UNIT
I_{Fast}	NORMAL Mode Current	System	2M ext. R/C		0.75	1	mA
I_{Slow}	SLOW Mode Current	System	32.768K X'tal LCD Disable		6	9	μA
I_{Idle}	IDLE Mode Current	System	32.769K X'tal LCD Disable		4	7	μA
I_{LCD}	Extra Current if LCD ON	System	LCD Enable		2	3	μA
I_{Sleep}	Sleep Mode Current	System				1	μA
I_{PWM}	PWM Output Current	PWMP, PWMN* ²	With 32Ω Loading	10	14		mA
			With 64Ω Loading	6	8		mA
			With 100Ω Loading	4	5		mA
I_{oVO}	DAC Output Current	VO	V _{DD} =3V; VO=0~2V, Data=7F	2.5	3		mA
V_{iH}	Input High Voltage	I/O pins		0.8 V _{DD}			V
V_{iL}	Input Low Voltage	I/O pins				0.2 V _{DD}	V
V_{hys}	Input Hysteresis Width	I/O, RSTP_N	Threshold=2/3V _{DD} (input from low to high) Threshold=1/3V _{DD} (input from high to low)		1/3 V _{DD}		V
I_{oH}	Output Drive Current	I/O pull-high* ¹	V _{oL} =2.0V	50			μA
I_{oL_1}	Output Sink Current	I/O pull-low* ¹	V _{oL} =0.4V	1.0			mA
I_{iL_1}	Input Low Current	RSTP_N	V _{iL} =GND, pull high Internally		20		μA
I_{iL_2}	Input Low Current	I/O	V _{iL} =GND, if pull high Internally by user		100		μA

Note: *1: Drive Current Spec. for Push-Pull I/O port only

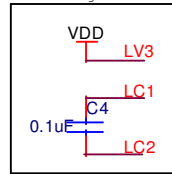
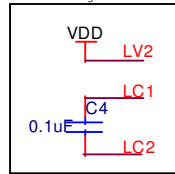
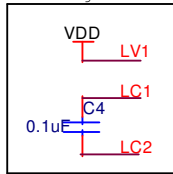
Sink Current Spec. for both Push-Pull and Open-Drain I/O port.

*2: This Spec. base on one driver only. There are five build-in driver, so user just multiply the number of driver he used to one driver current to get the total amount of current.

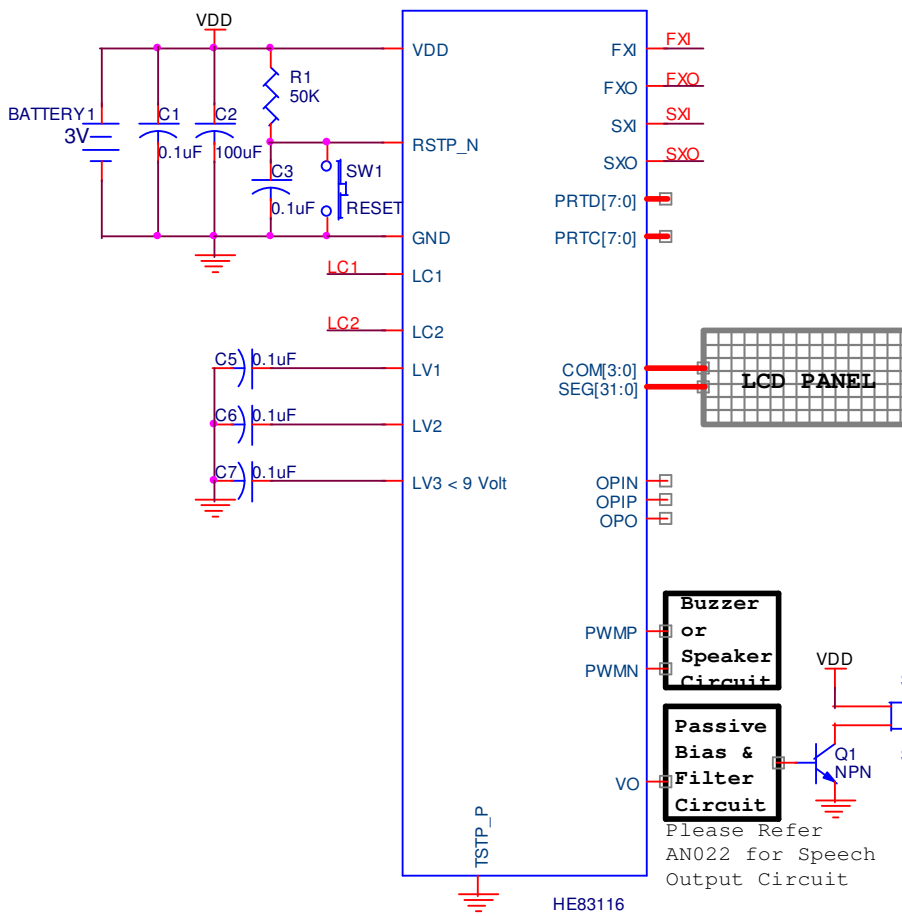
(I_{PWM} * N; N=0,1,2,3,4,5)

I. Application Circuit

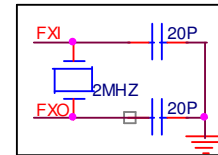
Tripple Charge Pump is selected Tripple Charge Pump is selected Tripple Charge Pump is selected
 LCD Max. Voltage=LV3=3*VDD LCD Max. Voltage=LV3=3/2*VDD LCD Max. Voltage=LV3=VDD



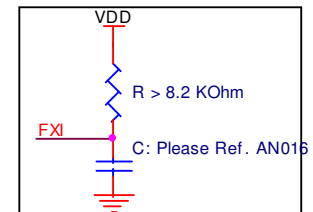
No External Parts is necessary if user adopt Internal Fast RC Clock



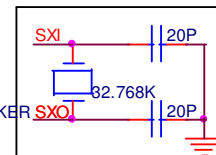
External Fast Clock: Crystal osc.



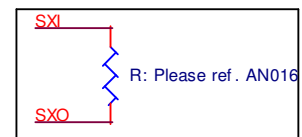
External Fast Clock: RC osc.



External Slow Clock: Crystal osc.

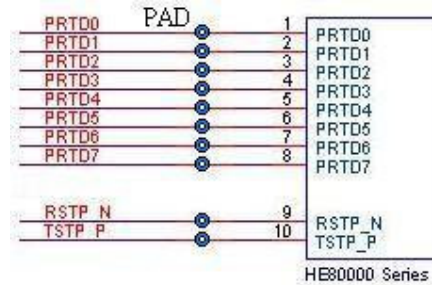


External Slow Clock: RC osc.



J. Important Note

1. LCD driving circuit must be turn off before IC goes into sleep mode.
2. Please bonds the TSTP_P, RSTP_N and PRTD[7:0] with test point on PCB (can be soldered and probed) as you can, then KB can do some IC testing job on PCB. Neither VDD nor GND connection is necessary for TSTP_P. The following figure is an example (Testing point with through hole).



3. LV3 must small than 9.0 Volt. Otherwise IC may breakdown.

K. Updated Record

Version	Date	Section	Original Content	New Content
V3.1	Dec 17,2001	B, H	2.2V (VDD operation voltage)	2.4V